

LM2902Q/LM2902AQ/LM2904Q/LM2904AQ

AUTOMOTIVE COMPLIANT DUAL AND QUAD OPERATIONAL AMPLIFIERS

Description

The LM2902Q/2904Q series operational amplifiers consist of four and two independent high-gain operational amplifiers with very low input offset voltage specification. They are designed to operate from a single power supply over a wide range of voltages; however, operation from split power supplies is also possible. They offer low power supply current independent of the magnitude of the power supply voltage.

The LM2904Q dual devices are available in SO-8, TSSOP-8 and MSOP-8; and the LM2902Q quad devices are available in SO-14 and TSSOP-14. All are in industry-standard pinouts, and both use "green" mold compound as standard.

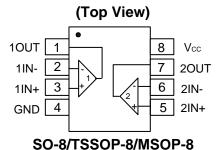
The LM2902Q/2904Q are characterized for operation from -40°C to +125°C, qualified to AEC-Q100 Grade 1 and are Automotive Compliant supporting PPAPs.

Features

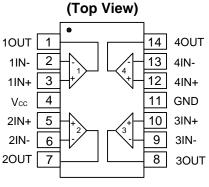
- Wide Power Supply Voltage Range:
 - Single Supply: 3V to 36V
 - Dual Supplies: ±1.5V to ±18V
- Very Low Supply Current Drain Independent of Supply Voltage
 - LM2904Q: 500µA
 - LM2902Q: 700µA
- Low Input Bias Current: 20nA
- Low Input Offset Voltage:
 - A Versions: 1mV (Typ)
 - Non-A Version: 2mV (Typ)
- Large DC Voltage Gain: 100dB
- Wide Bandwidth (Unity Gain): 700kHz (Temperature Compensated)
- Internally Compensated with Unity Gain
- Input Common-Mode Voltage Range Includes Ground
- Differential Input Voltage Range Equal to Power Supply Voltage
- Large Output Voltage Swing: 0V to V_{CC} -1.5V
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q100 Grade 1
- PPAP Capable (Note 4)

Pin Assignments

LM2904Q/LM2904QA



LM2902Q/LM2902QA



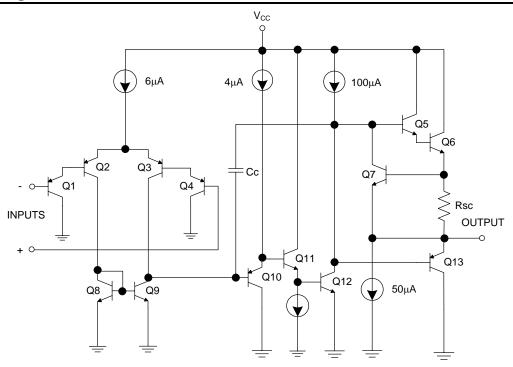
SO-14/TSSOP-14

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q100 qualified and are PPAP capable. Refer to http://www.diodes.com/quality/product_compliance_definitions/.



Schematic Diagram



Functional Block Diagram of LM2902Q/ 2902AQ/ 2904Q/ 2904AQ (Each Amplifier)

Pin Descriptions

LM2902Q, LM2902	AQ		
Pin Name	Pin#	Function	
1OUT	1	Channel 1 Output	
1IN-	2	Channel 1 Inverting Input	
1IN+	3	Channel 1 Non-Inverting Input	
Vcc	4	Chip Supply Voltage	
2IN+	5	Channel 2 Non-Inverting Input	
2IN-	6	Channel 2 Inverting Input	
2OUT	7	Channel 2 Output	
3OUT	8	Channel 3 Output	
3IN-	9	Channel 3 Inverting Input	
3IN+	10	Channel 3 Non-inverting Input	
GND	11	Ground	
4IN+	12	Channel 4 Non-Inverting Input	
4IN-	13	Channel 4 Inverting Input	
4OUT	14	Channel 4 Output	
LM2904Q, LM2904	AQ		
1OUT	1	Channel 1 Output	
1IN-	2	Channel 1 Inverting Input	
1IN+	3	Channel 1 Non-inverting Input	
GND	4	Ground	
2IN+	5	Channel 2 Non-Inverting Input	
2IN-	6	Channel 2 Inverting Input	
2OUT	7	Channel 2 Output	
Vcc	8	Chip Supply Voltage	



Absolute Maximum Ratings (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parar	neter	Rating	Unit
Vcc	Supply Voltage		±18 or 36	V
V _{ID}	Differential Input Voltage		36	V
VIN	Input Voltage		-0.3 to +36	V
		LM2904_QS-13	150	
	Danks on Thomas I law adopted	LM2904_QTH-13	175	
θ_{JA}	Package Thermal Impedance (Note 6) LM2904_QM8-13 LM2902_QS14	LM2904_QM8-13	200	°C/W
		LM2902_QS14	89	
		LM2902_QT14	100	
_	Output Short-Circuit to GND (One Amplifier) (Note 7)	$1/_{00} \le 15$ \land $1_{0} = \pm 25$ °C		_
T _A	Operating Temperature Range		-40 to +125	°C
TJ	Operating Junction Temperature		+150	°C
T _{ST}	Storage Temperature Range		-65 to +150	°C

Notes:

ESD Ratings

	LM2901_QS14	500	
	LM2901_QT14	500	
Human Body Mode ESD Protection (Note 8)	LM2903_QS-13	500	
	LM2903_QTH-13	500	
	LM2903_QM8-13	<500	V
	LM2901_QS14		V
	LM2901_QT14		
Charge Device Mode ESD Protection	LM2903_QS-13	1,000	
	LM2903_QTH-13		
	LM2903_QM8-13		

Note:

8. Human body model, 1.5kΩ in series with 100pF.

Recommended Operating Conditions (Over Operating Free-Air Temperature Range, unless otherwise noted.)

Para	Min	Max	Units	
Cumply Voltage	Single Supply	2	36	
Supply Voltage	Dual Supply	±1	±18	V
Ambient Temperature Range	-40	+125	°C	
Junction Temperature Range	-40	+125		

^{5.} Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{6.} Maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of +150°C can affect reliability.

^{7.} Short circuits from outputs to V_{CC} or ground can cause excessive heating and eventual destruction.



Electrical Characteristics (Notes 12 & 13) (@ V_{CC} = +5.0V, T_A = +25°C, unless otherwise specified.)

LM2902Q, LM2902AQ

	Parameter		Conditions		TA	Min	Тур	Max	Unit	
			V _{IC} = V _{CMR} Min,	Non-A	T _A = +25°C	_	2	7		
V	Innut Offact Valtage		$V_O = 1.4V$,	Device	Full Range	_	_	10	mV	
V_{IO}	Input Offset Voltage		V _{CC} = 5V to Max	A-Suffix	T _A = +25°C	_	1	2	IIIV	
			$R_S = 0\Omega$	Device	Full Range	_	_	4		
$\Delta V_{IO}/\Delta T$	Input Offset Voltage To Drift	emperature	$R_S = 0\Omega$		Full Range	_	7	_	μV/°C	
lΒ	Input Bias Current		I _{IN+} or I _{IN} - with OUT in L	inear Range,	T _A = +25°C	_	-20	-200	nA	
IB	Input bias Current		$V_{CMR} = 0V \text{ (Note 9)}$		Full Range	_	_	-500	IIA	
lio	Input Offset Current		I _{IN+} - I _{IN-} , V _{CM} = 0V		$T_A = +25$ °C	_	2	50	nA	
lio			IIN+ - IIN-, VCM = UV		Full Range	_	_	150	IIA	
$\Delta I_{IO}/\Delta T$	Input Offset Current Te Drift	emperature	_		Full Range	_	10	_	pA/°C	
V _{CMR}	Input Common-Mode	/oltage	V _{CC} = 30V (Note 10)		T _A = +25°C	0 to V _{CC} -1.5	_	_	V	
VCMR	Range		VCC = 30V (Note 10)		Full Range	0 to V _{CC} -2.0	-	_	V	
	Supply Current	oly Current $V_O = 0.5 V_{CC}$, No Load $V_{CC} = 30V$ Full	Full Range	_	1.0	3.0	A			
Icc	(Four Amplifiers)		$V_O = 0.5 V_{CC}$, No Load	V _{CC} = 5V	Full Range	_	0.7	1.2	.2 mA	
۸	W-W Q-'-		$V_{CC} = 15V$, $V_{OUT} = 1V$ to	11V,	1V, $T_A = +25^{\circ}C$		100	_	V/mV	
A_V	Voltage Gain		$R_L \ge 2k\Omega$ Full		Full Range	15	_	_	V/IIIV	
CMRR	Common Mode Reject	ion Ratio	DC, $V_{CMR} = 0V$ to V_{CC} -1	.5V	T _A = +25°C	60	70	_	dB	
PSRR	Power Supply Rejection	n Ratio	$V_{CC} = 5V \text{ to } 30V$		T _A = +25°C	70	100	_	dB	
_	Amplifier to Amplifier C	Coupling	f = 1kHz to 20kHz (Input Referred) (Note 11)		T _A = +25°C		-120	_	dB	
		Sink	$V_{IN-} = 1V$, $V_{IN+} = 0V$, V_{CO} $V_{O} = 200 \text{mV}$	c= 15V,	T _A = +25°C	12	50	_	μΑ	
Isink	Output Current	SILIK	$V_{IN-} = 1V, V_{IN+} = 0V, V_{C}$	c = 15V,	T _A = +25°C	10	20	_		
	Output Current		V _O = 15V		Full Range	5	_	_	mA	
laaaa		Source	$V_{IN+} = 1V, V_{IN-} = 0V, V_{CO}$	c= 15V,	$T_A = +25$ °C	-20	-40	-60		
I _{SOURCE}		Cource	$V_0 = 0V$		Full Range	-10	_	_		
I _{SC}	Short-Circuit to Ground	t	V _{CC} = 5V, GND = -5V, V _O = 0V		$T_A = +25^{\circ}C$	_	±40	±60	mA	
			$R_L = 10k\Omega$	$R_L = 10k\Omega$		_	V _{CC} -1.5]	
V_{OH}	High-Level Output Vol	Level Output Voltage Swing $R_L = 2k\Omega$	2kΩ	Full Range	26	_		V		
			$V_{CC} = 30V$ $R_L \ge 1$	0kΩ	1 dii ixange	27	28	_		
VoL	Low-Lever Output Volt	age Swing	$R_L \leqq 10k\Omega$		Full Range	_	5	20	mV	

AC Electrical Characteristics (Notes 12 & 13) (@ $V_{CC} = \pm 15.0V$, $T_A = +25$ °C, unless otherwise specified.)

	Parameter	Conditions	Тур	Unit
SR	Slew Rate at Unity Gain	$R_L = 1M\Omega$, $C_L = 30pF$, $V_I = \pm 10V$	0.3	V/µs
B1	Unity Gain Bandwidth	$R_L = 1M\Omega$, $C_L = 20pF$	0.7	MHz
Vn	Equivalent Input Noise Voltage	$R_S = 100\Omega$, $V_I = 0V$, $f = 1kHz$	40	nV/√Hz

Notes:

- 9. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so that no loading change exists on the input lines.
- 10. The input common-mode voltage of either input signal voltage should not be allowed to become negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is V_{CC} -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of V_{CC}.
- 11. Due to proximity of external components, ensure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.
- 12. Typical values are all at T_A = +25°C conditions and represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- 13. All limits are guaranteed by testing or statistical analysis. Limits over the full temperature (-40 ≤ T_A ≤ +125°C) are guaranteed by design, but not tested in production.



Electrical Characteristics (continued) (Notes 12 & 13) (@ V_{CC} = +5.0V, T_A = +25°C, unless otherwise specified.)

LM2904Q, LM2904AQ

	Parameter	•	Conditions		T _A	Min	Тур	Max	Unit		
			V _{IC} = V _{CMR} Min,	Non	-A Device	T _A = +25°C	_	2	7		
V	Input Offset Volt	200	$V_0 = 1.4V,$	NON	-A Device	Full Range	_	_	10	m∨	
V _{IO}	V _{IO} Impat onset voltage		$V_{CC} = 5V$ to MAX	۸ ج	uffix Device	T _A = +25°C	_	1	2	IIIV	
			$R_S = 0\Omega$	A-30	ullix Device	Full Range	_	_	4		
ΔV _{IO} /ΔΤ	Input Offset Volt Drift	age Temperature	$R_S = 0\Omega$			Full Range	_	7	_	μV/°C	
IB	Input Bias Curre	nt	I _{IN+} or I _{IN} - with OUT	Γ in Line	ar Range,	T _A = +25°C	_	-20	-250	nA	
IB	Input Bias Curre	TIL	V _{CMR} = 0V (Note 9))		Full Range	_	_	-500	IIA	
I _{IO}	Input Offset Curi	rent	I _{IN+} - I _{IN-} , V _{CM} = 0V			$T_A = +25$ °C	_	2	50	nA	
110	input Onset Cun	- CIII	11N+ - 11N-, VCM = UV			Full Range	_	_	150	ПА	
ΔΙ _{ΙΟ} /ΔΤ	Input Offset Curi Drift	rent Temperature		_		Full Range	_	10	_	pA/°C	
	Input Common-N	Mode Voltage				T _A = +25°C	0 to V _{CC} -1.5	-	_		
V _{CMR}	Range		V _{CC} = 30V (Note 10	` ,		Full Range	0 to V _{CC} -2.0	_	_	- V	
	Supply Current (Two Amplifiers)		Supply Current	$V_O = 0.5 V_{CC}$, No Lo	oad	V _{CC} = 30V	Full Range	_	0.7	2.0	^
Icc			$V_O = 0.5 V_{CC}$, No Lo	oad	$V_{CC} = 5V$	Full Range	_	0.5	1.2	mA	
	Valta na Cain		$V_{CC} = 15V$, $V_{OUT} = 1V$ to $11V$, $R_L \ge 2k\Omega$,		T _A = +25°C	25	100	_	\//ma\/		
A _V	Voltage Gain				Full Range	15	_	_	- V/mV		
CMRR	Common Mode	Rejection Ratio	DC, $V_{CMR} = 0V$ to	V _{CC} -1.5	V	T _A = +25°C	60	70	_	dB	
PSRR	Power Supply R	ejection Ratio	V _{CC} = 5V to 30V		T _A = +25°C	70	100	_	dB		
	Amplifier to Amp	lifier Coupling	f = 1kHz to 20kHz (Note 11)		T _A = +25°C	_	120	_	dB		
			$V_{IN-} = 1V, V_{IN+} = 0V$ $V_O = 200mV$	', V _{CC} = '	15V,	T _A = +25°C	12	50	_	μA	
Isink	0.1	Sink	$V_{IN-} = 1V, V_{IN+} = 0V$	', V _{CC} = '	15V,	T _A = +25°C	10	20	_		
	Output Current		V _O = 15V			Full Range	5	_	_		
	0		$V_{IN+} = 1V, V_{IN-} = 0V$	', Vcc = '	15V,	T _A = +25°C	-20	-40	-60	mA mA	
ISOURCE		Source	$V_0 = 0V$			Full Range	-10	_	_		
I _{SC}	Short-Circuit to Ground		V _{CC} = 5V, GND = -5V, V _O = 0V		T _A = +25°C	_	±40	±60	mA		
			$R_L = 10k\Omega$		T _A = +25°C	V _{CC} -1.5	_	_			
V _{OH}	High-Level Outp	n-Level Output Voltage Swing $R_L = 2k\Omega$)	Full Dones	26	_	_	V			
			V _{CC} = 30V	R _L ≥ 10k	Ω	Full Range	27	28	_		
V _{OL}	Low-Lever Outp	ut Voltage Swing	$R_L \leq 10k\Omega$			Full Range	_	5	20	mV	

AC Electrical Characteristics (Notes 12 & 13) (@ V_{CC} = ±15.0V, T_A = +25°C, unless otherwise specified.)

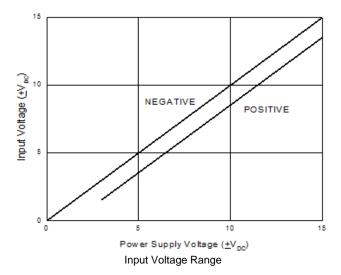
	Parameter Conditions		Тур	Unit
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B1	Unity Gain Bandwidth	$R_L = 1M\Omega$, $C_L = 20pF$	0.7	MHz
Vn	Equivalent Input Noise Voltage	$R_S = 100\Omega$, $V_I = 0V$, $f = 1kHz$	40	nV/√Hz

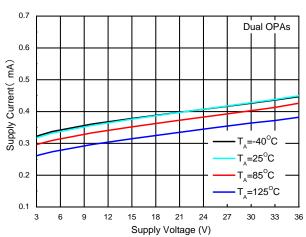
Notes:

- 9. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so that no loading change exists on the input lines.
- 10. The input common-mode voltage of either input signal voltage should not be allowed to become negative by more than 0.3V (@ +25°C). The upper end of the common-mode voltage range is V_{CC} -1.5V (@ +25°C), but either or both inputs can go to +36V without damage, independent of the magnitude of V_{CC}
- 11. Due to proximity of external components, ensure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.
- 12. Typical values are all at TA = +25°C conditions and represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
- 13. All limits are guaranteed by testing or statistical analysis. Limits over the full temperature (-40 ≤ T_A ≤ +125°C) are guaranteed by design, but not tested in production.

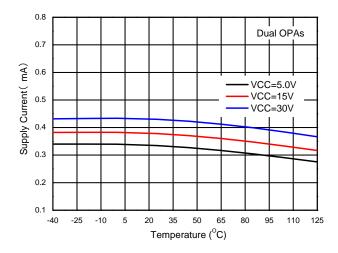


Performance Characteristics

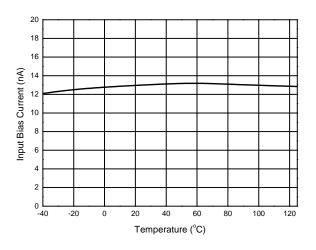




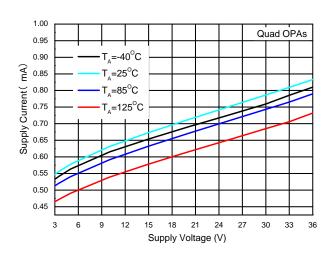
Supply Current vs. Supply Voltage (LM2904Q/4AQ)



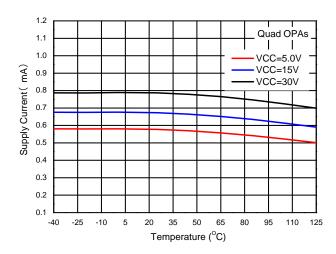
Supply Current vs. Temperature (LM2904Q/AQ)



Input Current



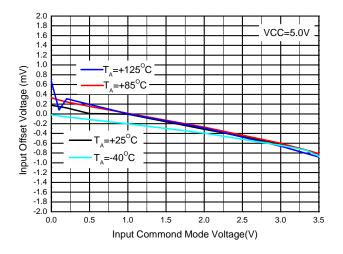
Supply Current vs. Supply Voltage (LM2902Q/AQ)

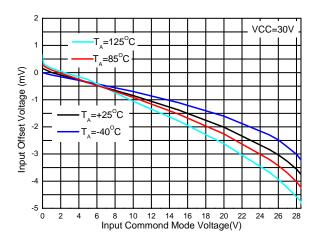


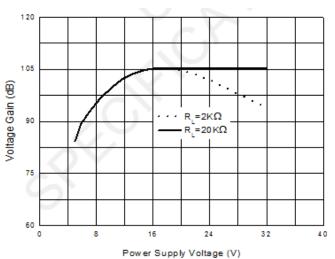
Supply Current vs. Temperature (LM2902Q/AQ)

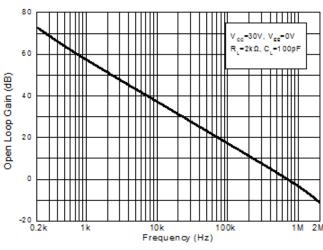


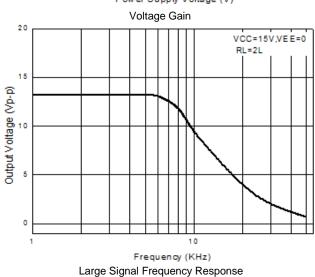
Performance Characteristics (continued)

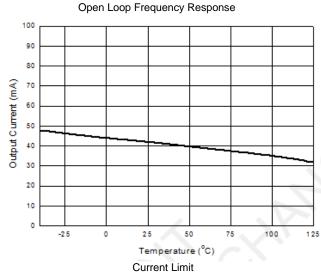






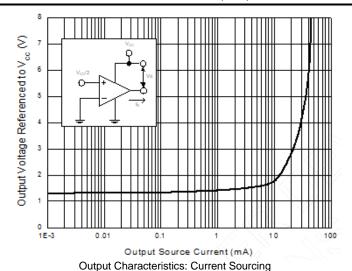


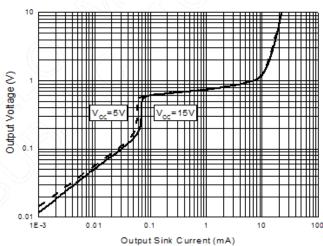




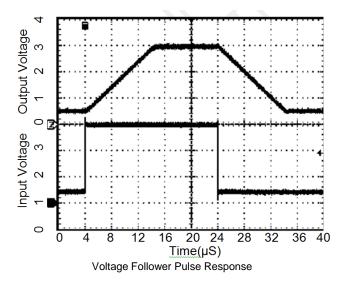


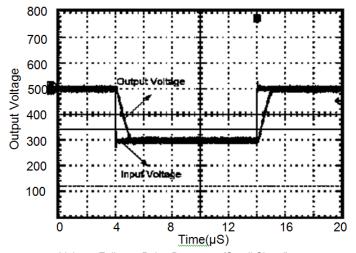
Performance Characteristics (cont.)





Output Characteristics: Current Sinking





Voltage Follower Pulse Response (Small Signal)

LM2902Q/LM2902AQ/LM2904Q/LM2904AQ



Application Information

General Information

The LM2902Q/2904Q series op amps which operate with only a single power supply voltage, have true-differential inputs and remain in the linear mode with an input common-mode voltage of 0 V_{DC} . These amplifiers operate over a wide range of power supply voltage with little change in performance characteristics. At +25°C, amplifier operation is possible down to a minimum supply voltage of 2.3 V_{DC} .

Precautions should be taken to ensure that the power supply for the integrated circuit never becomes reversed in polarity, or that the unit is not inadvertently installed backwards in a test socket. If precaution is not taken, an unlimited current surge through the resulting forward diode within the IC may occur and could cause fusing of the internal conductors, destroying the unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V^+ without damaging the device. Protection should be provided to prevent the input voltages from becoming negative more than -0.3 V_{DC} (@ +25°C). An input clamp diode with a resistor to the IC input terminal can be used.

To reduce the power supply current drain, the amplifiers have a class A output stage for small signal levels which converts to class B in a large signal mode. This allows the amplifiers to both source and sink large output currents. Therefore both NPN and PNP external current boost transistors can be used to extend the power capability of the basic amplifiers. The output voltage needs to raise approximately 1 diode drop above ground to bias the on-chip vertical PNP transistor for output current sinking applications.

For AC applications where the load is capacitive coupled to the output of the amplifier, a resistor should be used from the output of the amplifier to ground to increase the class A bias current, and prevent crossover distortion. Where the load is directly coupled, as in DC applications, there is no crossover distortion.

Capacitive loads which are applied directly to the output of the amplifier reduce the loop stability margin. Values of 50pF can be accommodated using the worst-case non-inverting unity gain connection. Large closed loop gains or resistive isolation should be used if larger load capacitance must be driven by the amplifier.

The bias network of the LM2902Q/2904Q series establishes a quiescent current which is independent of the magnitude of the power supply voltage over the range of 3 V_{DC} to 30 V_{DC}.

Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive function temperatures. Putting direct short-circuits on more than one amplifier at a time will increase the total IC power dissipation to destructive levels, if not properly protected with external dissipation limiting resistors in series with the output leads of the amplifiers. The larger value of output source current which is available at +25°C provides a larger output current capability at elevated temperatures (see Typical Performance Characteristics) than a standard IC op amp.

The circuits presented in Typical Applications section emphasize operation on a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference of V_{CC}/2) will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.



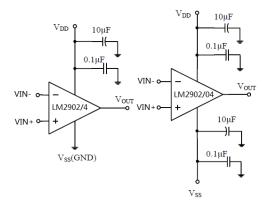
Application Information (continued)

Power Supply Bypassing and Layout

The LM2902Q/04Qxx family operates from both single supply voltage range 3 to 36V, or dual supply voltage ±1.5V to ±18V.

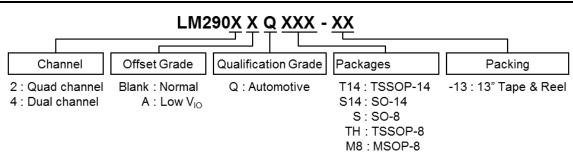
As with any operation amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. For single supply operation system, a minimum 0.1µF bypass capacitor should be recommended to place as close as possible between V_{CC} pin and GND. For dual supply operation, both the positive supply pin and negative supply pin should be bypassed to ground with a separate 0.1µF ceramic capacitor.

2.2µF tantalum capacitor can be added for better performance. Keep the length of leads and traces that connect capacitors between LM29xx power supply pin and ground as short as possible.



Amplifier with Bypass Capacitors

Ordering Information



Part Number	Package	Packaging	13" Tape and Reel		Qualification
Part Number	Code	(Note 14)	Quantity	Part Number Suffix	(Note 15)
LM2902QT14-13	T14	TSSOP-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2902AQT14-13	T14	TSSOP-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2902QS14-13	S14	SO-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2902AQS14-13	S14	SO-14	2,500/Tape & Reel	-13	Automotive Compliant
LM2904QS-13	S	SO-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904AQS-13	S	SO-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904QTH-13	TH	TSSOP-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904AQTH-13	TH	TSSOP-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904QM8-13	M8	MSOP-8	2,500/Tape & Reel	-13	Automotive Compliant
LM2904AQM8-13	M8	MSOP-8	2,500/Tape & Reel	-13	Automotive Compliant

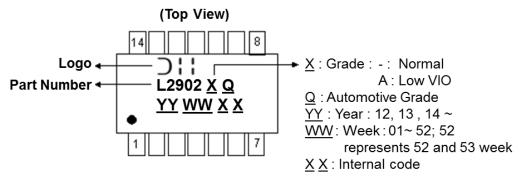
Notes: 14. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

^{15.} LM2902Q/2904Q have been qualified to AEC-Q100 grade 1 and are classified as "Automotive Compliant" which supports PPAP documentation. See LM2902/2904 datasheet for commercial qualified versions.

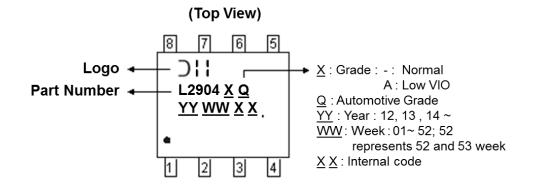


Marking Information

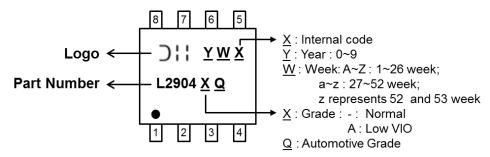
(1) TSSOP-14 and SO-14



(2) SO-8



(3) MSOP-8 and TSSOP-8

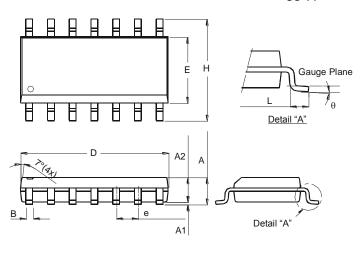




Package Outline Dimensions

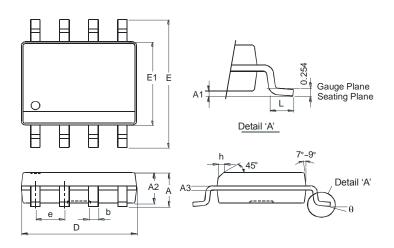
Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-14



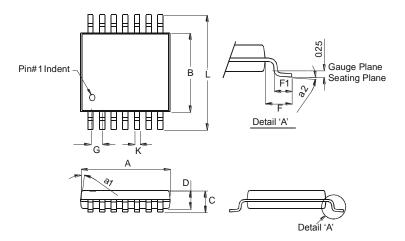
	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
В	0.33	0.51				
D	8.53	8.74				
Е	3.80	3.99				
е	1.27	Тур				
Н	5.80	6.20				
L	0.38	1.27				
θ	0°	8°				
All Di	All Dimensions in mm					

SO-8



	SO-8	
Dim	Min	Max
Α	_	1.75
A 1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
Е	5.90	6.10
E1	3.85	3.95
е	1.27	Тур
h		0.35
L	0.62	0.82
θ	0°	8°
All Di	mensions	s in mm

TSSOP-14



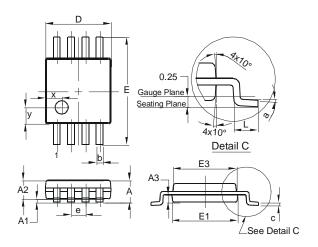
	TSSOP-14				
Dim	Min	Max			
a1	7° (4X)			
a2	0°	8°			
Α	4.9	5.10			
В	4.30	4.50			
С	_	1.2			
D	0.8	1.05			
F	1.00	Тур			
F1	0.45	0.75			
G	0.65	Тур			
K	0.19	0.30			
L 6.40 Typ					
All Dir	nensions	s in mm			



Package Outline Dimensions (continued)

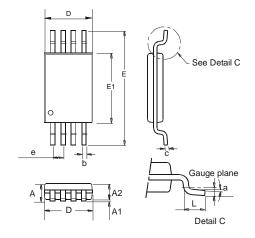
Please see http://www.diodes.com/package-outlines.html for the latest version.

MSOP-8



MSOP-8			
Dim	Min	Max	Тур
Α	ī	1.10	-
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
A3	0.29	0.49	0.39
b	0.22	0.38	0.30
С	0.08	0.23	0.15
D	2.90	3.10	3.00
Е	4.70	5.10	4.90
E1	2.90	3.10	3.00
E 3	2.85	3.05	2.95
е	ı	1	0.65
L	0.40	0.80	0.60
а	0°	8°	4°
X	-	-	0.750
у	ı	1	0.750
All Dimensions in mm			

TSSOP-8



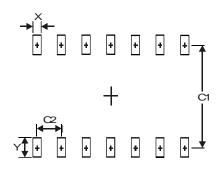
TSSOP-8			
Dim	Min	Max	Тур
а	0.09	_	_
Α	_	1.20	_
A1	0.05	0.15	_
A2	0.825	1.025	0.925
b	0.19	0.30	_
С	0.09	0.20	_
D	2.90	3.10	3.025
е			0.65
Е	_	_	6.40
E1	4.30	4.50	4.425
L	0.45	0.75	0.60
All Dimensions in mm			



Suggested Pad Layout

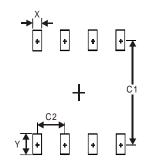
Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-14



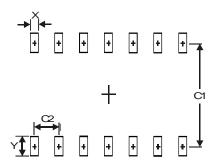
Dimensions	Value (in mm)
X	0.60
Υ	1.50
C1	5.4
C2	1.27

SO-8



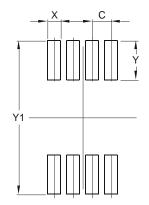
Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

TSSOP-14



Dimensions	Value (in mm)
X	0.45
Υ	1.45
C1	5.9
C2	0.65

MSOP-8



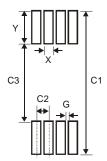
Dimensions	Value (in mm)
С	0.650
Х	0.450
Y	1.350
Y1	5.300



Suggested Pad Layout (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSSOP-8



Dimensions	Value (in mm)
Х	0.45
Υ	1.78
C1	7.72
C2	0.65
C3	4.16
G	0.20

LM2902Q/LM2902AQ/LM2904Q/LM2904AQ



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